

Application Data Sheet**Application Information**

Application Type:: Regular
Subject Matter:: Utility
Title:: Trench MOSFET Having Implanted Drain-Drift
Region And Process For Manufacturing The Same
Attorney Docket Number:: SCX010-5D US
Request for Early Publication?:: No
Request for Non-Publication?:: No
Total Drawing Sheets:: 18
Small Entity?:: No
Petition Included?:: No
Secrecy Order in Parent Appl.?:: No

Applicant Information

Applicant Authority Type:: Inventor
Primary Citizenship Country:: US
Status:: Full Capacity
Given Name:: Mohamed
Middle Name:: N.
Family Name:: Darwish
Name Suffix::
City of Residence:: Campbell
State or Province of Residence:: California
Country of Residence:: US
Street of Mailing Address:: 675 Regas Drive
City of Mailing Address:: Campbell
State or Province of Mailing Address:: California
Country of Mailing Address:: US
Postal or Zip Code of mailing 95008

address::

Correspondence Information

Correspondence Customer Number:: 34036

Representative Information

Representative Customer Number::	34036
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Domestic Priority Information

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This application	Divisional of	10/317,568	12/12/02
10/317,568	Continuation in part of	09/898,652	07/03/01

Assignee Information

Assignee Name:: Siliconix incorporated
Street of Mailing Address:: 2201 Laurelwood Road
City of Mailing Address:: Santa Clara
State of Mailing Address:: California
Country of Mailing Address:: USA
Zip Code of Mailing Address:: 95054